

MOSFETs Silicon N-channel MOS (U-MOSVII-H)

# SSM6K341NU

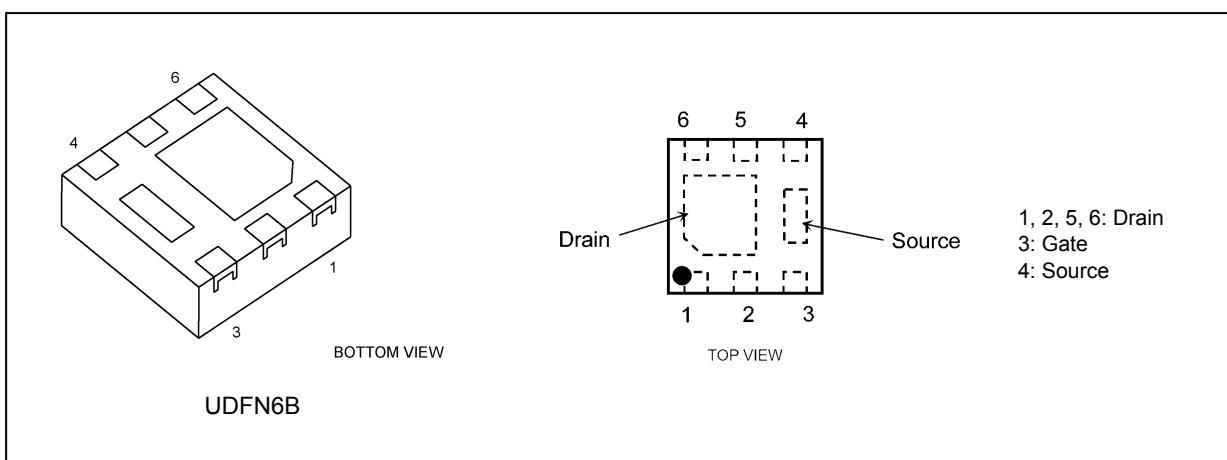
## 1. Applications

- Power Management Switches
- DC-DC Converters

## 2. Features

- (1) 4.0 V drive
- (2) Low drain-source on-resistance
  - :  $R_{DS(ON)} = 28 \text{ m}\Omega$  (typ.) (@ $V_{GS} = 10 \text{ V}$ )
  - $R_{DS(ON)} = 36 \text{ m}\Omega$  (typ.) (@ $V_{GS} = 4.5 \text{ V}$ )
  - $R_{DS(ON)} = 43 \text{ m}\Omega$  (typ.) (@ $V_{GS} = 4 \text{ V}$ )

## 3. Packaging and Pin Assignment



Start of commercial production  
2016-12

#### 4. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	60	V
Gate-source voltage	$V_{GSS}$	$\pm 20$	
Drain current (DC)	(Note 1)	$I_D$	A
Drain current (pulsed)	(Note 1), (Note 2)	$I_{DP}$	
Power dissipation	(Note 3)	$P_D$	W
Power dissipation	( $t \leq 10\text{ s}$ )	(Note 3)	
Single-pulse avalanche energy	(Note 4)	$E_{AS}$	mJ
Avalanche current	$I_{AR}$	6	A
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: pulse width  $\leq 1\text{ ms}$ , Duty  $\leq 1\%$

Note 3: Device mounted on a 25.4 mm  $\times$  25.4 mm  $\times$  1.6 mm FR4 glass epoxy board (Cu pad: 645 mm<sup>2</sup>)

Note 4:  $V_{DD} = 25\text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$  (Initial state),  $L = 1\text{ mH}$ ,  $R_G = 25\text{ }\Omega$

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance,  $R_{th(ch-a)}$ , and the drain power dissipation,  $P_D$ , vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

#### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-ambient thermal resistance (Note 1)	$R_{th(ch-a)}$	100	$^\circ\text{C/W}$

Note 1: Device mounted on an 25.4 mm  $\times$  25.4 mm  $\times$  1.6 mm FR4 glass epoxy board (Cu pad: 645 mm<sup>2</sup>)

## 6. Electrical Characteristics

### 6.1. Static Characteristics (Unless otherwise specified, $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 16 \text{ V}$	—	—	$\pm 10$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$	—	—	1	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	60	—	—	
Drain-source breakdown voltage (Note 1)	$V_{(BR)DSX}$	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	40	—	—	
Gate threshold voltage (Note 2)	$V_{th}$	$V_{DS} = 10 \text{ V}, I_D = 0.1 \text{ mA}$	1.5	—	2.5	
Drain-source on-resistance (Note 3)	$R_{DS(\text{ON})}$	$I_D = 2 \text{ A}, V_{GS} = 4 \text{ V}$	—	43	69	
		$I_D = 3 \text{ A}, V_{GS} = 4.5 \text{ V}$	—	36	51	$\text{m}\Omega$
		$I_D = 4 \text{ A}, V_{GS} = 10 \text{ V}$	—	28	36	

Note 1: If a reverse bias is applied between gate and source, this device enters  $V_{(BR)DSX}$  mode. Note that the drain-source breakdown voltage is lowered in this mode.

Note 2: Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current ( $I_D$ ) to below (0.1 mA for this device). Then, for normal switching operation,  $V_{GS(\text{ON})}$  must be higher than  $V_{th}$ , and  $V_{GS(\text{OFF})}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(\text{OFF})} < V_{th} < V_{GS(\text{ON})}$ .

Take this into consideration when using the device.

Note 3: Pulse measurement.

### 6.2. Dynamic Characteristics (Unless otherwise specified, $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	$C_{iss}$	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	—	550	—	$\text{pF}$
Reverse transfer capacitance	$C_{rss}$		—	35	—	
Output capacitance	$C_{oss}$		—	300	—	
Switching time (rise time)	$t_r$	$V_{DD} = 30 \text{ V}, I_D = 3 \text{ A}, V_{GS} = 0 \text{ to } 4.5 \text{ V}, R_{GS} = 50 \Omega$ Duty $\leq 1\%$ , Input: $t_r, t_f < 5 \text{ ns}$ , Common source, See Chapter 6.3.	—	48	—	$\text{ns}$
Switching time (turn-on time)	$t_{on}$		—	63	—	
Switching time (fall time)	$t_f$		—	6	—	
Switching time (turn-off time)	$t_{off}$		—	18	—	

### 6.3. Switching Time Test Circuit

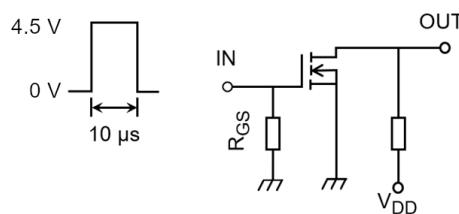


Fig. 6.3.1 Switching Time Test Circuit

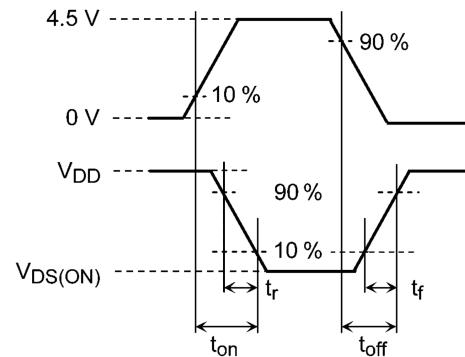


Fig. 6.3.2 Input Waveform/Output Waveform

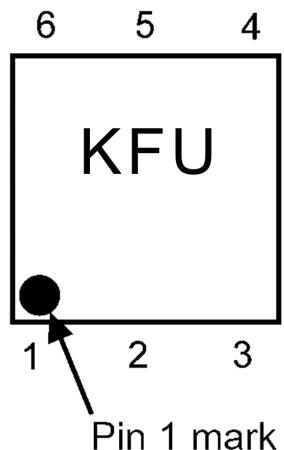
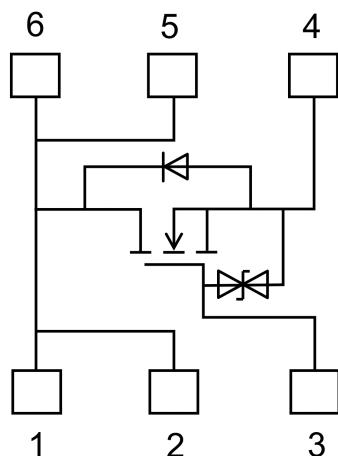
### 6.4. Gate Charge Characteristics (Unless otherwise specified, $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} = 48 \text{ V}, I_D = 2 \text{ A}, V_{GS} = 10 \text{ V}$	—	9.3	—	$\text{nC}$
Gate-source charge 1	$Q_{gs1}$		—	1.8	—	
Gate-drain charge	$Q_{gd}$		—	2.0	—	

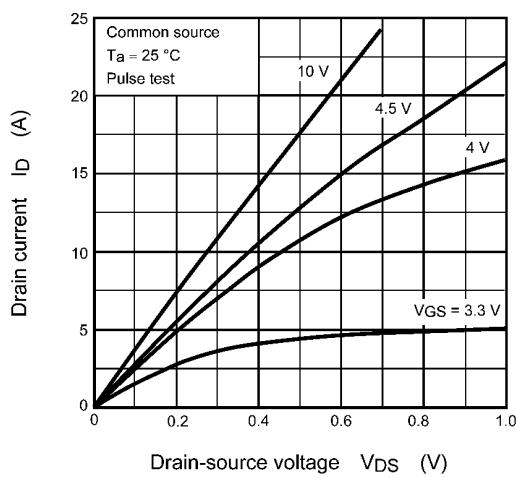
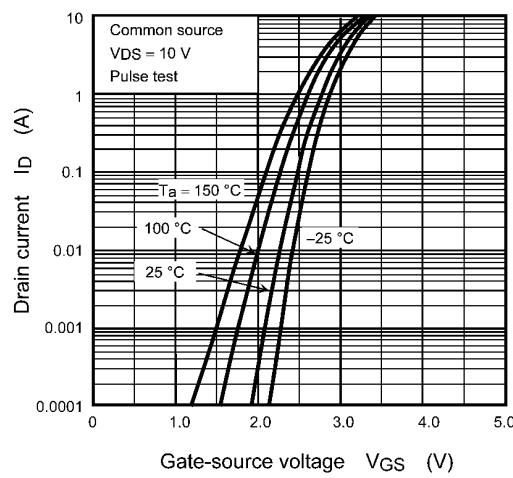
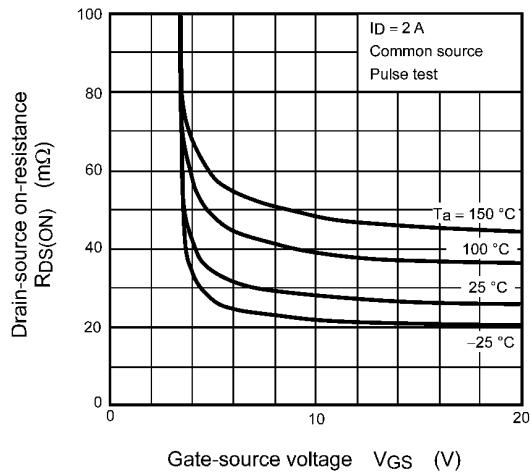
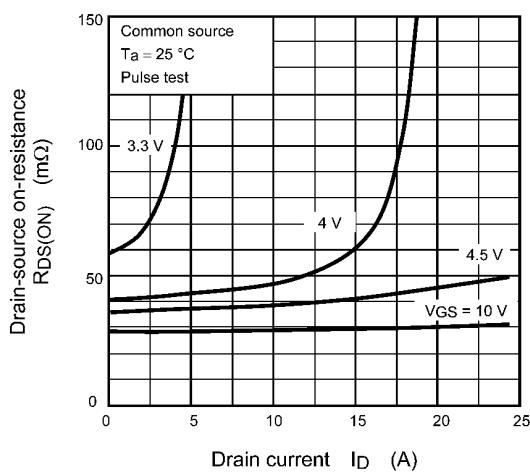
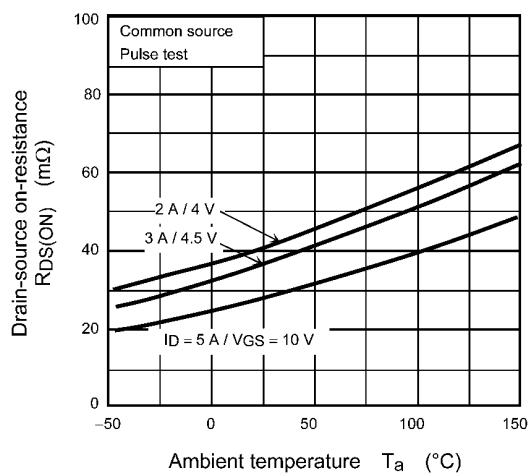
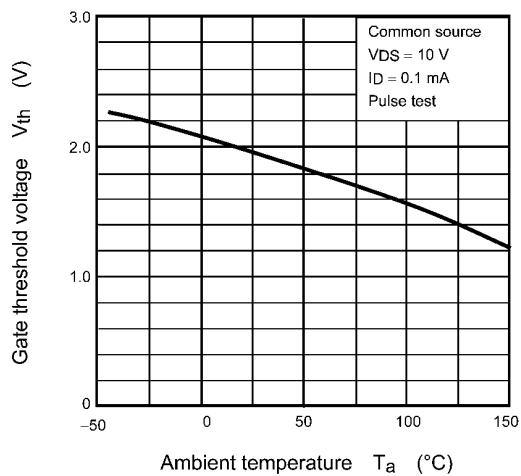
**6.5. Source-Drain Characteristics (Unless otherwise specified,  $T_a = 25^\circ\text{C}$ )**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Diode forward voltage (Note 1)	$V_{DSF}$	$I_{DR} = 4 \text{ A}, V_{GS} = 0 \text{ V}$	—	0.84	1.5	V

Note 1: Pulse measurement.

**7. Marking****8. Internal Circuit**

## 9. Characteristics Curves (Note)

Fig. 9.1  $I_D - V_{DS}$ Fig. 9.2  $I_D - V_{GS}$ Fig. 9.3  $R_{DS(ON)} - V_{GS}$ Fig. 9.4  $R_{DS(ON)} - I_D$ Fig. 9.5  $R_{DS(ON)} - T_a$ Fig. 9.6  $V_{th} - T_a$

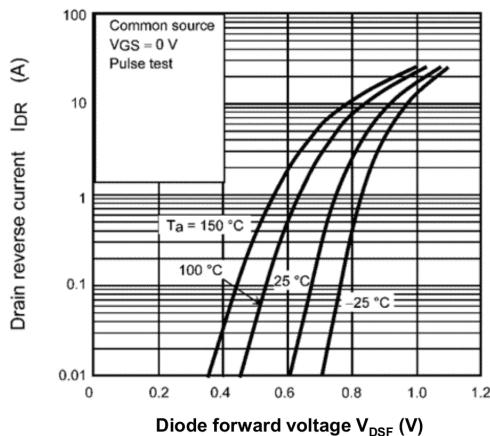


Fig. 9.7  $I_{DR}$  -  $V_{DSF}$

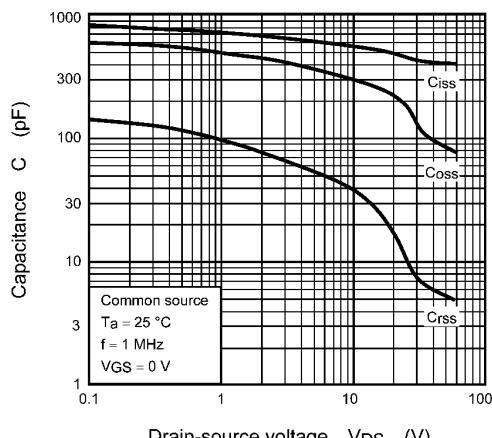


Fig. 9.8  $C$  -  $V_{DS}$

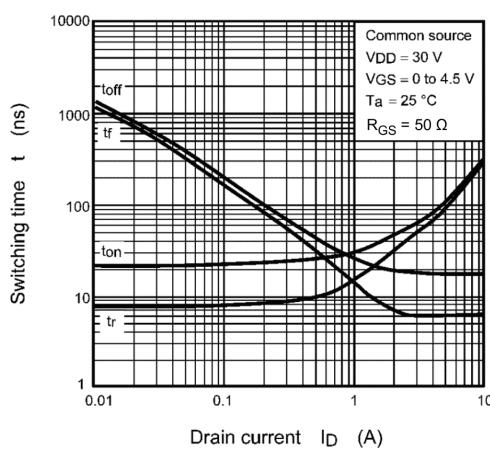


Fig. 9.9  $t$  -  $I_D$

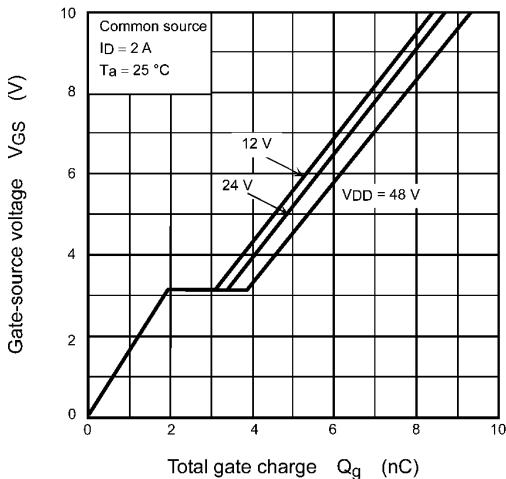


Fig. 9.10 Dynamic Input Characteristics

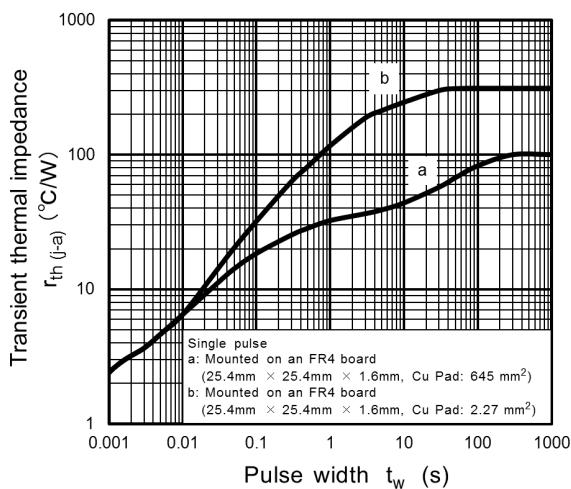


Fig. 9.11  $r_{th}$  -  $t_w$

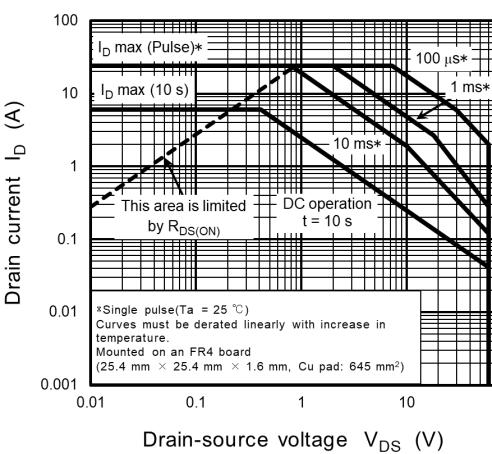
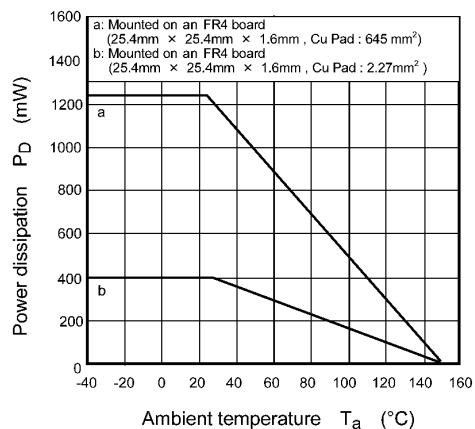


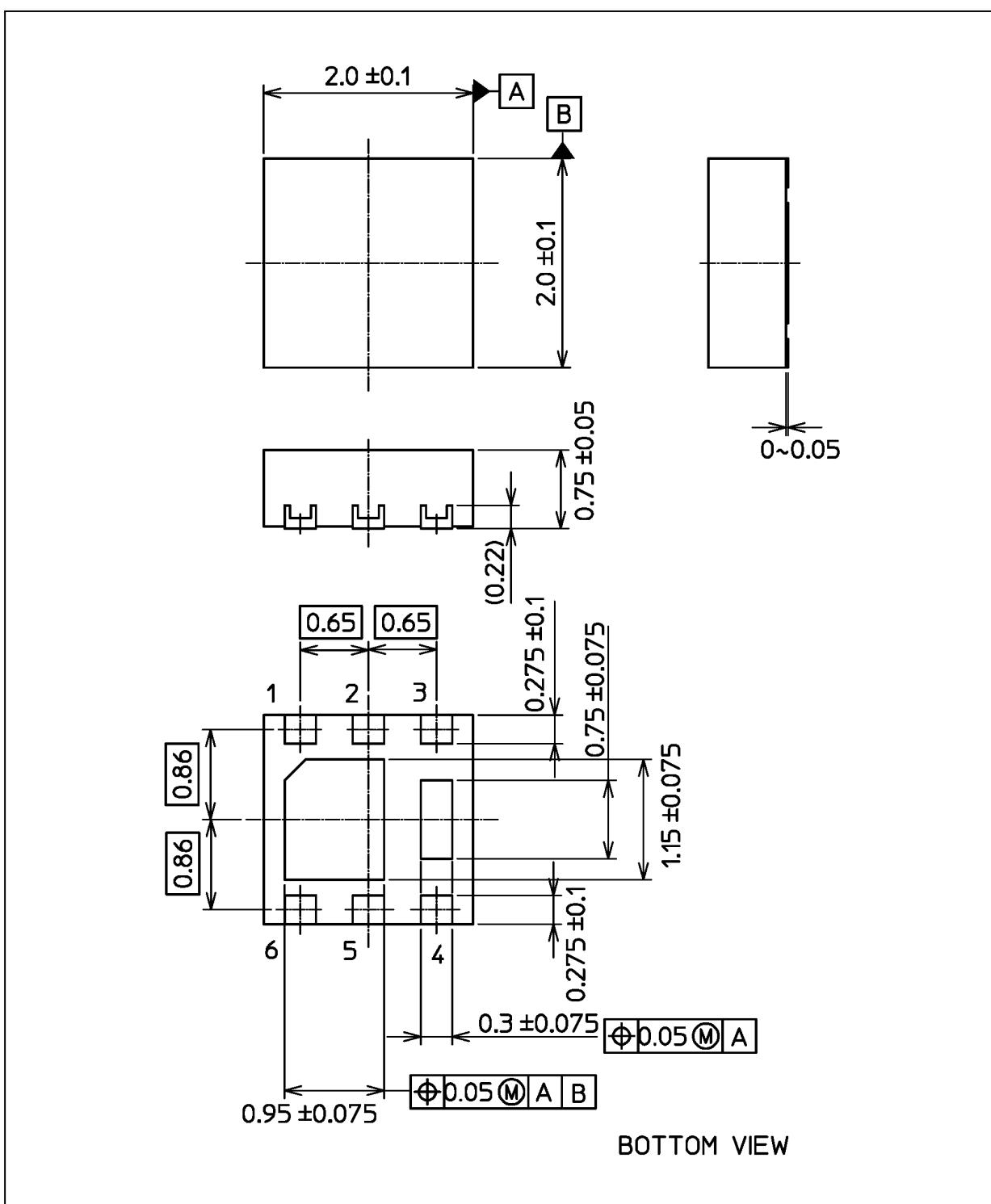
Fig. 9.12 Safe Operating Area

**Fig. 9.13  $P_D - T_a$** 

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

## Package Dimensions

Unit: mm



Weight: 8.5 mg (typ.)

Package Name(s)
JEDEC: SOT-1220
Nickname: UDFN6B

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